74HC4050

Hex non-inverting HIGH-to-LOW level shifter Rev. 3 — 31 January 2013

Product data sheet

1. **General description**

The 74HC4050 is a hex buffer with over-voltage tolerant inputs. Inputs are overvoltage tolerant to 15 V which enables the device to be used in HIGH-to-LOW level shifting applications.

Features and benefits 2.

- Low-power dissipation
- Complies with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2 000 V
 - ♦ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

Ordering information 3.

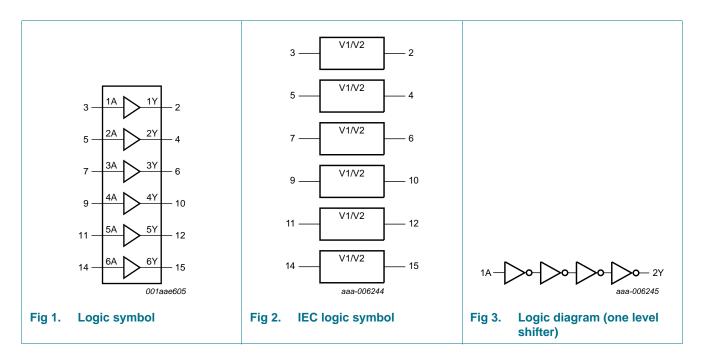
Table 1. **Ordering information**

Type number	Package								
	Temperature range	Name	Description	Version					
74HC4050N	–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4					
74HC4050D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					
74HC4050DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1					
74HC4050PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1					



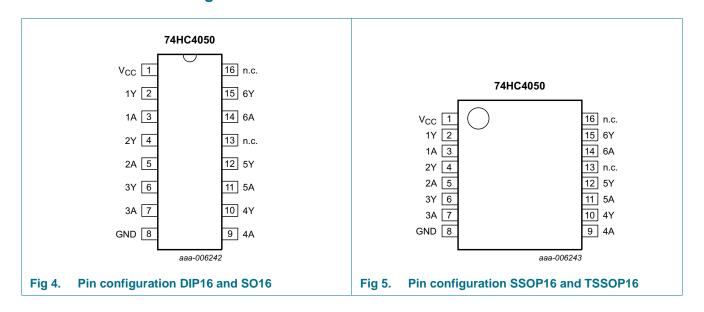
Hex non-inverting HIGH-to-LOW level shifter

4. Functional diagram



5. Pinning information

5.1 Pinning



Hex non-inverting HIGH-to-LOW level shifter

5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
V_{CC}	1	supply voltage
1Y to 6Y	2, 4, 6, 10, 12, 15	output
1A to 6A	3, 5, 7, 9, 11, 14	input
GND	8	ground (0 V)
n.c.	13, 16	not connected

6. Functional description

Table 3. Function table [1]

Input	Output
nA	nY
L	L
Н	Н

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

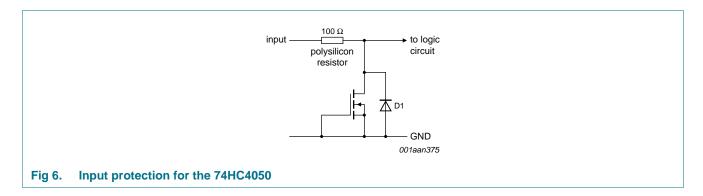
In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Parameter	Conditions	Min	Max	Unit
supply voltage		-0.5	+7	V
input clamping voltage		-0.5	+16	V
input clamping current	$V_{I} < -0.5 \text{ V}$	-20	-	mA
output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	-	±20	mA
output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±25	mA
supply current		-	+50	mA
ground current		-	-50	mA
storage temperature		-65	+150	°C
total power dissipation	DIP16 package	<u>[1]</u> -	750	mW
	SO16, SSOP16 and TSSOP16 packages	<u>[2]</u> -	500	mW
	supply voltage input clamping voltage input clamping current output clamping current output current supply current ground current storage temperature	supply voltage input clamping voltage input clamping current $V_I < -0.5 \text{ V}$ output clamping current $V_O < -0.5 \text{ V}$ or $V_O > V_{CC} + 0.5 \text{ V}$ output current $V_O = -0.5 \text{ V}$ to $V_C = -0.5 \text{ V}$ to $V_C = -0.5 \text{ V}$ supply current ground current storage temperature total power dissipation DIP16 package	supply voltage -0.5 input clamping voltage -0.5 input clamping current $V_1 < -0.5 \text{ V}$ -20 output clamping current $V_0 < -0.5 \text{ V}$ or $V_0 > V_{CC} + 0.5 \text{ V}$ $-$ output current $V_0 = -0.5 \text{ V}$ to $(V_{CC} + 0.5 \text{ V})$ $-$ supply current $-$ ground current $-$ storage temperature -65 total power dissipationDIP16 package	supply voltage -0.5 $+7$ input clamping voltage -0.5 $+16$ input clamping current $V_1 < -0.5 \text{ V}$ -20 -20 output clamping current $V_0 < -0.5 \text{ V}$ or $V_0 > V_{CC} + 0.5 \text{ V}$ $ \pm 20$ output current $V_0 = -0.5 \text{ V}$ to $(V_{CC} + 0.5 \text{ V})$ $ \pm 25$ supply current $ +50$ ground current $ -50$ storage temperature -65 $+150$ total power dissipationDIP16 package 11 $ -$

^[1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 $^{\circ}\text{C}.$

^[2] For SO16 packages: P_{tot} derates linearly with 8 mW/K above 70 °C. For SSOP16 and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

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8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		2.0	5.0	6.0	V
V_{I}	input voltage		0	-	15	V
Vo	output voltage		0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}; V_{I} = 2.0 \text{ V}$	-	-	625	ns/V
		$V_{CC} = 4.5 \text{ V}; V_I = 4.5 \text{ V}$	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}; V_I = 6.0 \text{ V}$	-	-	83	ns/V
		$V_{CC} = 6.0 \text{ V}; V_I = 10.0 \text{ V}$	-	-	81	ns/V
		$V_{CC} = 6.0 \text{ V}; V_I = 15.0 \text{ V}$	-	-	83	ns/V

9. Static characteristics

 Table 6.
 Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions	T _{amb} = 25 °C			T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	Ī
V _{IH} HIGH-level input voltage		$V_{CC} = 2.0 \text{ V}$	1.5	1.3	-	1.5	-	1.5	-	V
	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V	
		$V_{CC} = 6.0 \text{ V}$	4.2	3.1	-	4.2	-	4.2	-	V
IL.	LOW-level input voltage	$V_{CC} = 2.0 \text{ V}$	-	0.7	0.5	-	0.5	-	0.5	V
		$V_{CC} = 4.5 \text{ V}$	-	1.8	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.3	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}								
		$I_O = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \mu A$; $V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	-	-	5.34	-	5.2	-	V

74HC4050

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Hex non-inverting HIGH-to-LOW level shifter

Table 6. Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Tai	T _{amb} = 25 °C		T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}								
		$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	-	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	-	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	-	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
		$V_I = 15 \text{ V}; V_{CC} = 2.0 \text{ V} \text{ to}$ 6.0 V	-	-	±0.5	-	±5.0	-	±5.0	μА
I _{CC}	supply current	V_I = 15 V or GND; I_O = 0 A; V_{CC} = 6.0 V	-	-	2.0	-	20	-	40	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see Figure 8.

Symbol	Parameter	eter Conditions		T _{ar}	T _{amb} = 25 °C		T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
				Min	Тур	Max	Min	Max	Min	Max	
t _{pd} r	propagation	nA to nY; see Figure 7	<u>[1]</u>								
	delay	$V_{CC} = 2.0 \text{ V}$		-	25	85	-	105	-	130	ns
		$V_{CC} = 4.5 \text{ V}$		-	9	17	-	21	-	26	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	7	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	7	14	-	18	-	22	ns
t _t	transition	Yn; see Figure 7	[2]								
	time	$V_{CC} = 2.0 \text{ V}$		-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 \text{ V}$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 \text{ V}$		-	6	13	-	16	-	19	ns

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 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see Figure 8.

Symbol	bol Parameter Conditions		T _{amb} = 25 °C		T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
C_{PD}	power dissipation capacitance	$C_L = 50 \text{ pF}; f = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	-	14	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [2] t_t is the same as t_{THL} and t_{TLH} .
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$

 f_i = input frequency in MHz;

fo = output frequency in MHz;

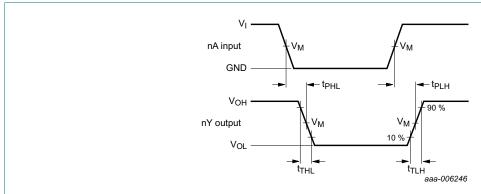
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

11. Waveforms



Measurement points are given in Table 8.

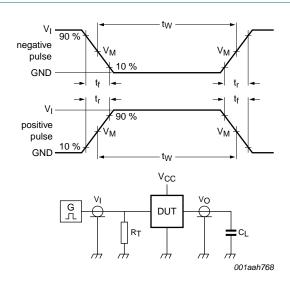
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 7. The input (nA) to output (nY) propagation delays

Table 8. Measurement points

Туре	Input	Output
	V _M	V _M
74HC4050	0.5V _{CC}	0.5V _{CC}

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Test data is given in Table 9.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

Fig 8. Test circuit for measuring switching times

Table 9. Test data

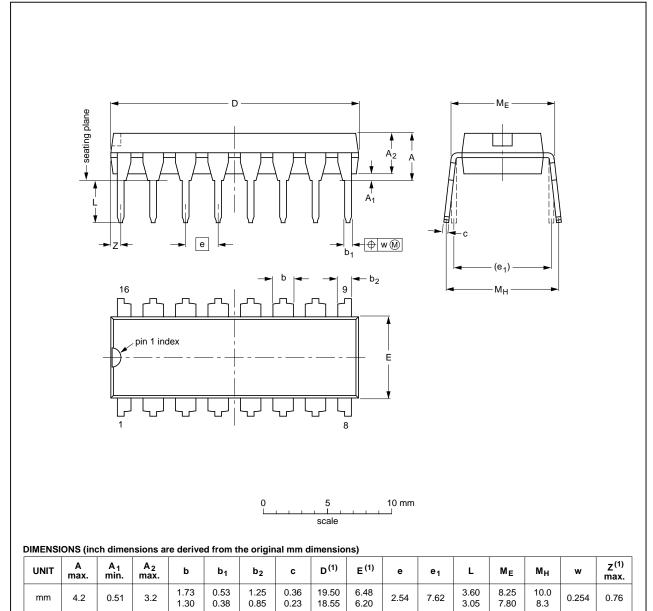
Туре	Input		Load	Test
	VI	t _r , t _f	CL	
74HC4050	V _{CC}	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

Hex non-inverting HIGH-to-LOW level shifter

12. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



inches 0.17 0.02

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

0.015

0.049

0.033

0.014

0.009

0.068

0.051

0.13

OUTLINE		REFER	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT38-4					95-01-14 03-02-13

0.77

0.26

0.1

0.3

0.14

0.32

Fig 9. Package outline SOT38-4 (DIP16)

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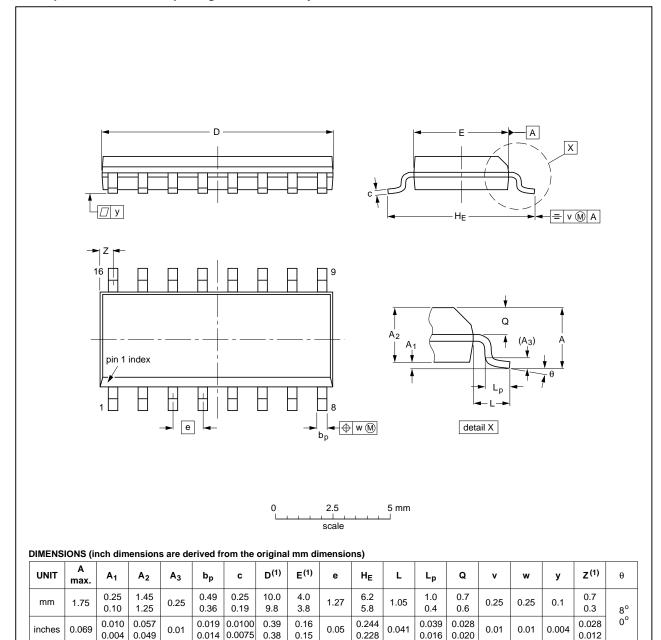
0.01

0.03

Hex non-inverting HIGH-to-LOW level shifter

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	1330E DATE	
SOT109-1	076E07	MS-012			99-12-27 03-02-19	

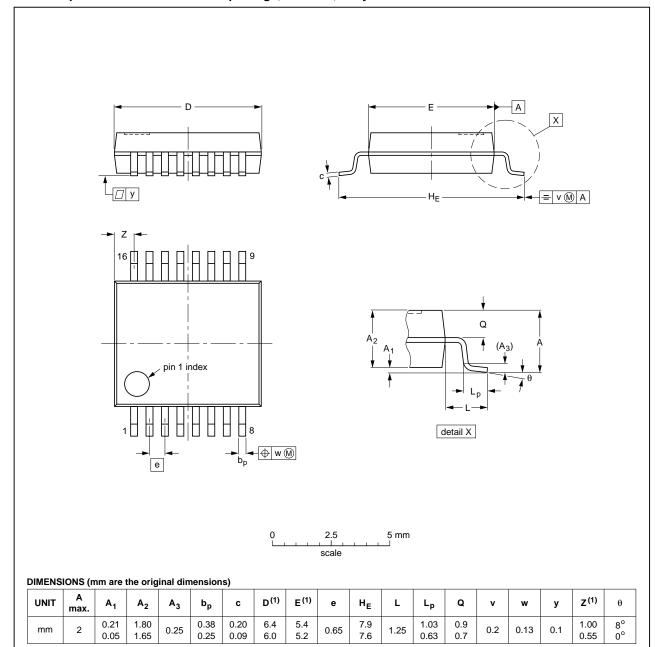
Fig 10. Package outline SOT109-1 (SO16)

74HC405

Hex non-inverting HIGH-to-LOW level shifter

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION		REFER	ENCES	EUROPEAN		
	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT338-1		MO-150			99-12-27 03-02-19	

Fig 11. Package outline SOT338-1 (SSOP16)

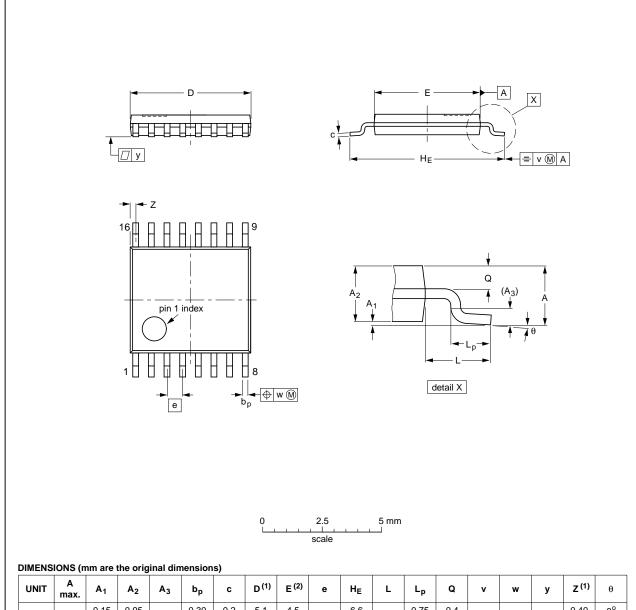
74HC405

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Hex non-inverting HIGH-to-LOW level shifter

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	v	w	У	Z (1)	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

PROJECTION ISSUE DATE
PROJECTION
99.12-27 03-02-18

Fig 12. Package outline SOT403-1 (TSSOP16)

Hex non-inverting HIGH-to-LOW level shifter

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC4050 v.3	20130131	Product data sheet	-	74HC4050_CNV v.2			
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 						
	 Legal texts 	s have been adapted to the	ne new company nam	e where appropriate.			
74HC4050_CNV v.2	19970826	Product specification	-	-			

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15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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